

Features

- \varnothing 500 μ m active area
- High QE for λ = 850-1064 nm
- Low noise
- Low slope multiplication curve

Description

Circular active area APD chip with IR enhanced sensitivity. Very low dark current due to guard ring diode. Metal can type hermetic TO5i package with clear glass window.

Application

- Pulsed 1064 nm laser detection
- Laser range finding
- Fluorescence detection

RoHS

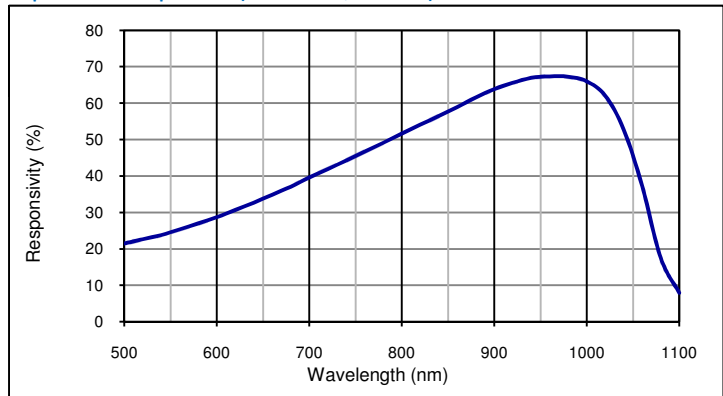
2002/95/EC



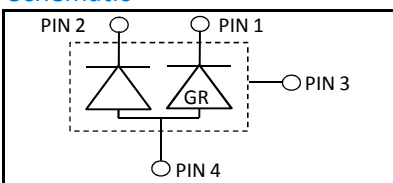
Absolute maximum ratings

Symbol	Parameter	Min	Max	Unit
T_{STG}	Storage temp	-55	125	$^{\circ}$ C
T_{OP}	Operating temp	-10	70	$^{\circ}$ C
M_{max}	Gain ($I_{PO} = 1$ nA)	1000		
I_{PEAK}	Peak DC current		0.25	mA

Spectral response (M = 100; 22 $^{\circ}$ C)



Schematic



Electro-optical characteristics @ 22 $^{\circ}$ C

Symbol	Characteristic	Test Condition	Min	Typ	Max	Unit
	Active area			\varnothing 500		μ m
	Active area			0.2		mm ²
I_D	Dark current	M = 100		1.5	10	nA
C	Capacitance	M = 100		0.5		pF
	Responsivity	M = 100; λ = 905 nm		65		A/W
	Responsivity	M = 100; λ = 1064 nm		36		A/W
t_R	Rise time	M = 100; λ = 1064 nm; $R_i = 50 \Omega$		4		ns
t_R	Cut-off frequency	-3dB		90		MHz
V_{BR}	Breakdown voltage	$I_R = 2 \mu$ A	220	300	550	V
	Temperature coefficient			3.3		V/K
	N.E.P.	M = 100; λ = 1064 nm		4 E-14		W/ \sqrt Hz
	Noise current	M = 100; λ = 1064 nm		1.5		pA/ \sqrt Hz

European, International Sales:



International AG

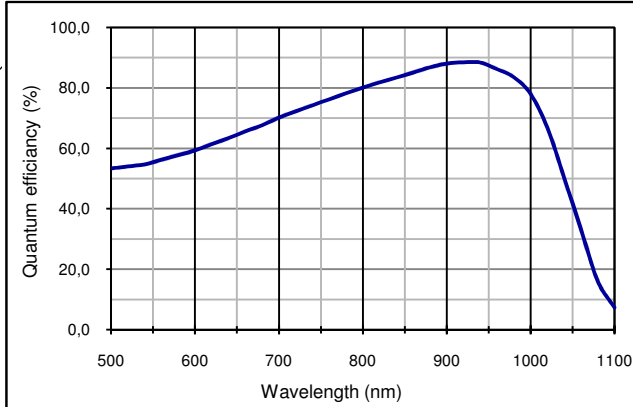
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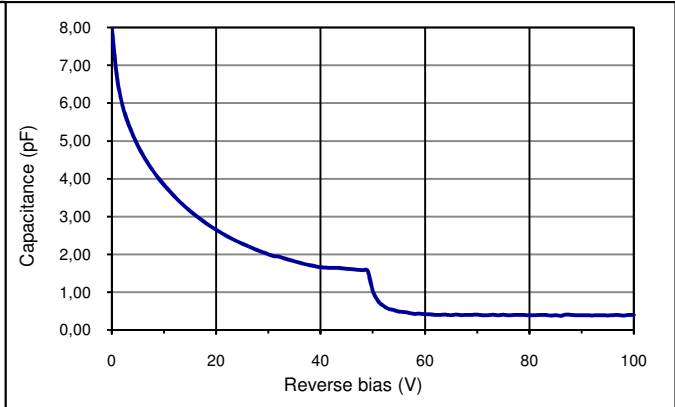


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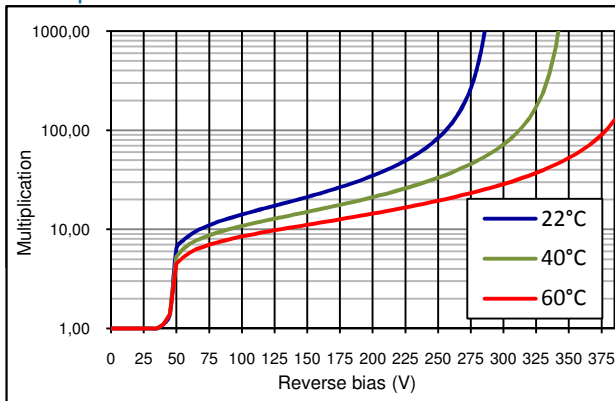
Quantum efficiency (22 °C)



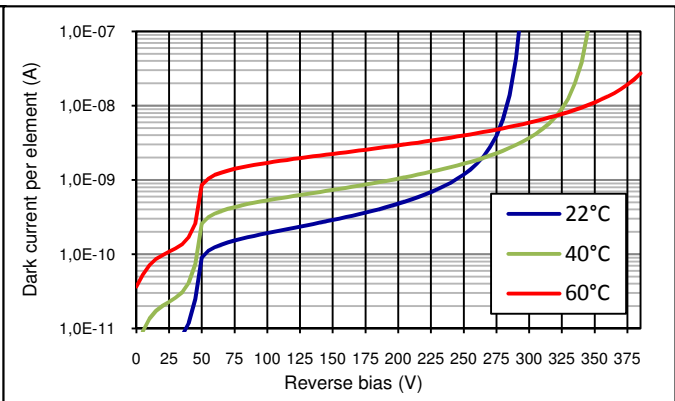
Capacitance as fct of reverse bias (22°C)



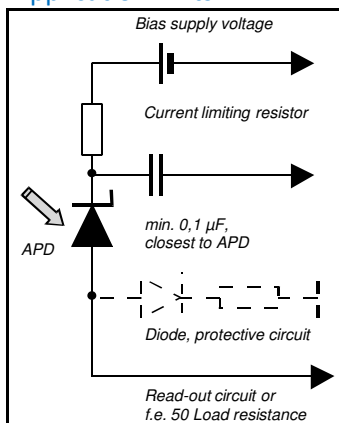
Multiplication as fct of reverse bias



Dark current as fct of reverse bias



Application hints:



- Current should be limited by a protecting resistor or current limiting - IC inside the power supply
- For low light level applications blocking of ambient light should be used
- For high gain applications bias voltage should be temperature compensated
- Please consider basic ESD protection while handling
- Use low noise read-out - IC
- For further questions please refer to document "Instructions for handling and processing"

Package dimension:

Small quantities: Foam pad, boxed (12 cm x 16.5 cm)

Disclaimer: Due to our strive for continuous improvement, specifications are subject to change within our PCN policy according to JESD46C.

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